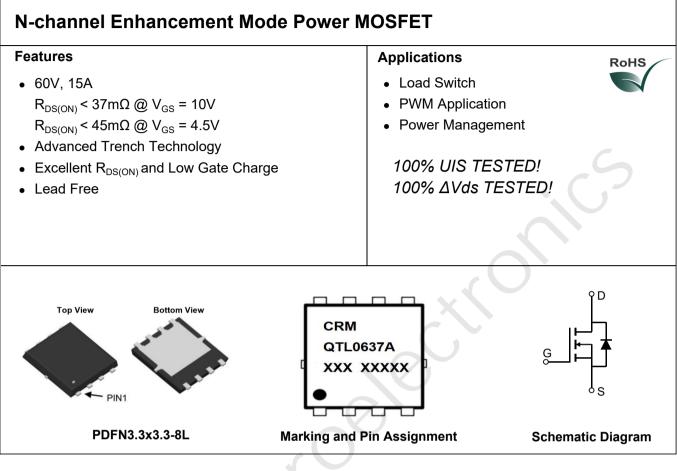


## Description



### Package Marking and Ordering Information

Device Marking	Device	Outline	Package	Reel Size	Reel(pcs)	Per Carton (pcs)
CRMQTL0637A	CRMQTL0637A	TAPING	PDFN3.3x3.3-8L	13"	5000	50000

#### Absolute Maximum Ratings (@ T<sub>c</sub> = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V <sub>DS</sub>	Drain-to-Source Voltage		60	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
	Continuous Darin Current	T <sub>C</sub> = 25°C	15	
Ι <sub>D</sub>	Continuous Drain Current	T <sub>C</sub> = 100°C	9	A
I <sub>DM</sub>	Pulsed Drain Current <sup>(1)</sup>		60	А
E <sub>AS</sub>	Single Pulsed Avalanche Energy	/ <sup>(2)</sup>	25	mJ
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25°C	20	W
R <sub>eJC</sub>	Thermal Resistance, Junction to C	Case	6.2	°C/W
$T_{J},T_{STG}$	Junction & Storage Temperature R	ange	-55 to 150	°C



#### Electrical Characteristics (T<sub>J</sub> = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics				<u> </u>	
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	60	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 60V, V_{GS} = 0V$	-	-	1.0	μΑ
I <sub>GSS</sub>	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
On Cha	iracteristics				C	
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1.1	1.6	2.1	V
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A	-	28.0	37.0	mΩ
R <sub>DS(ON)</sub>	Static Drain-Source ON-Resistance <sup>(4)</sup>	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 5A	-	34.0	45.0	mΩ
Dynam	ic Characteristics					
C <sub>iss</sub>	Input Capacitance		-	860	-	pF
C <sub>oss</sub>	Output Capacitance	$V_{GS} = 0V, V_{DS} = 25V,$	-	62	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz		51	-	pF
$Q_{g}$	Total Gate Charge			20.3	-	nC
Q <sub>gs</sub>	Gate Source Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DS} = 30V, I_D = 10A$	<u> </u>	3.7	-	nC
$Q_{gd}$	Gate Drain("Miller") Charge	$v_{DS} = 30v, i_D = 10A$	-	5.3	-	nC
	·					
Switch	ing Characteristics					
t <sub>d(on)</sub>	Turn-On DelayTime		-	6	-	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>GS</sub> = 10V, V <sub>DD</sub> = 30V	-	6	-	ns
$t_{d(off)}$	Turn-Off DelayTime	$I_D$ = 5A, $R_{GEN}$ = 1.8 $\Omega$	-	19	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	3	-	ns
Drain-S	ource Diode Characteristics and I	Max Ratings				
ا <sub>s</sub>	Maximum Continuous Drain to Source Diod	de Forward Current	-	-	15	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Fo	prward Current	-	-	60	А
$V_{\rm SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 10A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time		-	13	-	ns
Qrr	Body Diode Reverse Recovery Charge	I <sub>F</sub> = 5A, di/dt = 100A/us	-	9	-	nC

Notes: 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2. E<sub>AS</sub> condition: Starting T<sub>J</sub>=25C, V<sub>DD</sub>=30V, V<sub>G</sub>=10V, R<sub>G</sub>=25ohm, L=0.5mH, I<sub>AS</sub>=10A

3. Pulse Test: Pulse Width  ${\leqslant}300\mu s,$  Duty Cycle  ${\leqslant}0.5\%.$ 



# CRMQTL0637A

## Test Circuit

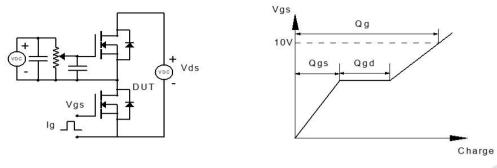


Figure 1: Gate Charge Test Circuit & Waveform

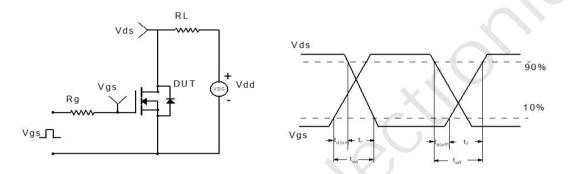
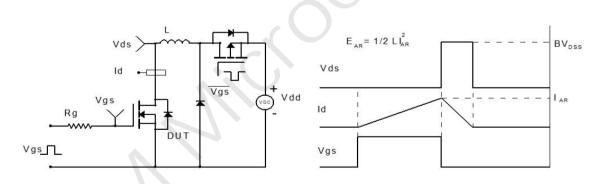
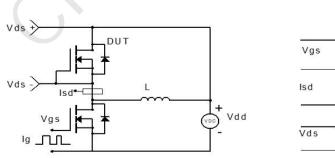
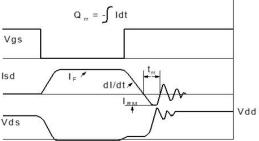


Figure 2: Resistive Switching Test Circuit & Waveform





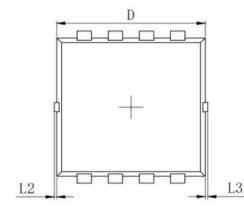


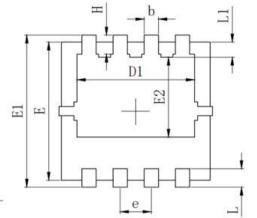




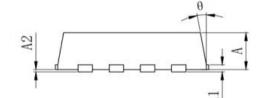


## Package Mechanical Data(PDFN3.3x3.3-8L)





caamoo .	MILLIMETER				
SYMBOL	MIN	Typ.	MAX		
A	0.700	0.800	0.900		
A1	0.152 REF.				
A2	0~0.05				
D	3.000	3.100	3.200		
D1	2.300	2.450	2.600		
Е	2.900	3.000	3.100		
E1	3.150	3,300	3,450		
E2	1.535	1.735	1.935		
b	0.200	0.300	0.400		
е	0.550	0.650	0.750		
L	0.300	0.400	0.500		
L1	0.180	0.330	0.480		
L2	0~0. 100				
L3	0~0.100				
Н	0.315	0.415	0.515		
θ	8°	10°	12°		



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